

APPA3010SF4C-P22

3.0 x 1.0 mm Infrared Emitting Diode



DESCRIPTION

 SF4 Made with Gallium Aluminum Arsenide Infrared Emitting diodes.

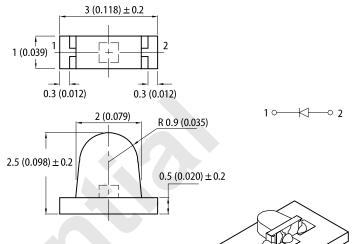
FEATURES

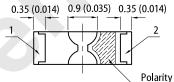
- 3.0 x 2.5 x 1.0mm right angle SMD LED, 1.0 mm thickness
- · Mechanically and spectrally matched to phototransistor
- Package: 2000 pcs / reel
- Moisture sensitivity level: 3
- · Tinned pads for improved solderability
- RoHS compliant

APPLICATIONS

- · Infrared Illumination for cameras
- · Machine vision systems
- · Surveillance systems
- · Industrial electronics
- IR data transmission
- · Remote control

PACKAGE DIMENSIONS

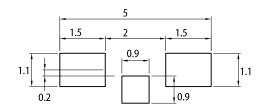




Polarity mark

RECOMMENDED SOLDERING PATTERN

(units: mm; tolerance: ± 0.1)



- 1. All dimensions are in millimeters (inches).
- Tolerance is ±0.15(0.006") unless otherwise noted.
 The specifications, characteristics and technical data described in the datasheet are subject to
- change without prior notice.

 4. The device has a single mounting surface. The device must be mounted according to the specifications

SELECTION GUIDE

Part Number	Emitting Color (Material)	Lens Type	Po (mW/sr) @ 20mA ^[2]		Viewing Angle [1]
			Min.	Тур.	201/2
APPA3010SF4C-P22	Infrared (GaAlAs)	Water Clear	1	2.5	30°

- Notes.

 1. 61/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.

 2. Radiant Intensity / luminous flux: +/-15%.

 3. Radiant intensity value is traceable to CIE127-2007 standards.





ELECTRICAL / OPTICAL CHARACTERISTICS at T_A=25°C

Parameter	Symbol	Emitting Color	Value		11
Parameter			Тур.	Max.	Unit
Wavelength at Peak Emission I _F = 20mA	λ_{peak}	Infrared	880	-	nm
Spectral Bandwidth at 50% Φ REL MAX I _F = 20mA	Δλ	Infrared	50	-	nm
Capacitance	С	Infrared	90	-	pF
Forward Voltage I _F = 20mA	V _F ^[1]	Infrared	1.3	1.6	V
Reverse Current (V _R = 5V)	I _R	Infrared		10	uA
Temperature Coefficient of Wavelength I_F = 20mA, -10°C \leq T \leq 85°C	TCA	Infrared	0.3	-	nm/°C
Temperature Coefficient of V_F I_F = 20mA, -10°C \leq T \leq 85°C	TC _V	Infrared	-1.3	-	mV/°C

1. Forward voltage: ±0.1V.
2. Wavelength value is traceable to CIE127-2007 standards.
3. Excess driving current and / or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

ABSOLUTE MAXIMUM RATINGS at T_A=25°C

Parameter	Symbol	Value	Unit
Power Dissipation	P _D	85	mW
Reverse Voltage	V_R	5	V
Junction Temperature	T _j	125	°C
Operating Temperature	T _{op}	-40 to +85	°C
Storage Temperature	T _{stg}	-40 to +85	°C
DC Forward Current	I _F	50	mA
Peak Forward Current	I _{FM} ^[1]	1200	mA
Electrostatic Discharge Threshold (HBM)	-	8000	V
Thermal Resistance (Junction / Ambient)	R _{th JA} ^[2]	315	°C/W
Thermal Resistance (Junction / Solder point)	R _{th JS} ^[2]	260	°C/W

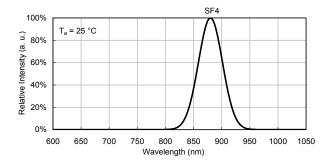
To the state of t



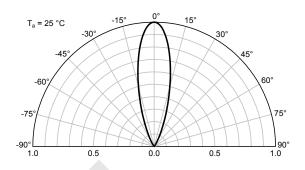


TECHNICAL DATA

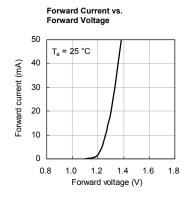
RELATIVE INTENSITY vs. WAVELENGTH

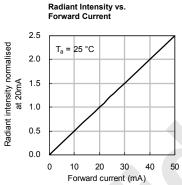


SPATIAL DISTRIBUTION



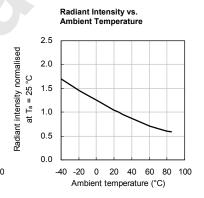
INFRARED



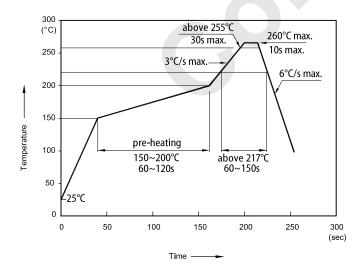


Permissible forward current (mA) 60 50 40 30 20 10 0 -20 0 20 40 60 80 100 Ambient temperature (°C)

Forward Current Derating Curve

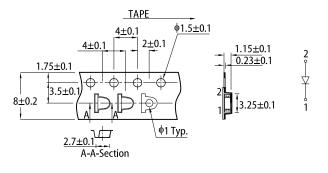


REFLOW SOLDERING PROFILE for LEAD-FREE SMD PROCESS

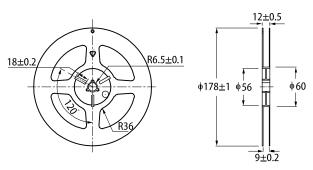


- Don't cause stress to the LEDs while it is exposed to high temperature.
- The maximum number of reflow soldering passes is 2 times.
 Reflow soldering is recommended. Other soldering methods are not recommended as they might cause damage to the product.

TAPE SPECIFICATIONS (units: mm)

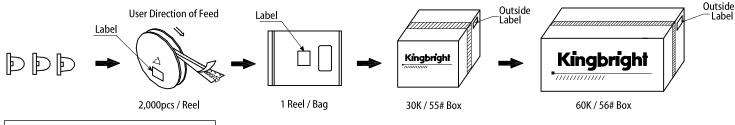


REEL DIMENSION (units: mm)





PACKING & LABEL SPECIFICATIONS





- The information included in this document reflects representative usage scenarios and is intended for technical reference only.

 The part number, type, and specifications mentioned in this document are subject to future change and improvement without notice. Before production usage customer should refer to the latest datasheet for the updated specifications.
- When using the products referenced in this document, please make sure the product is being operated within the environmental and electrical limits specified in the datasheet. If customer usage exceeds the specified limits, Kingbright will not be responsible for any subsequent issues.

 The information in this document applies to typical usage in consumer electronics applications. If customer's application has special reliability requirements or have life-threatening
- liabilities, such as automotive or medical usage, please consult with Kingbright representative for further assistance. The contents and information of this document may not be reproduced or re-transmitted without permission by Kingbright. All design applications should refer to Kingbright application notes available at https://www.KingbrightUSA.com/Application1



X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Infrared Emitters category:

Click to view products by Kingbright manufacturer:

Other Similar products are found below:

LTE-309 LTE-3279K LTE-4206C LTE-4208C EAILP03RDAA6 LTE-2871C LTE-4238 ASDL-4264-C22 OED-EL305F4C50-HT OP216-004 LTE-3376 EEL109 HL-PST-1608IR1C-L4 SFH 7016 IN-S126ETIR IN-S126DSHIR IN-S126ETHIR IN-P32ZTHIR IN-S42CTQHIR IN-S126BTHIR IN-S63DTHIR IN-S85BTHIR IN-S63FTHIR EAIST3535A1 EAIST3535A4 MHT153IRCT MHS153IRCT HIR204C/H0 HIR323C LTE-209 HSDL-4400#011 IR12-21C/TR8 IR17-21C/TR8 IR26-21C/L110/TR8 IR91-21C/TR10 KM-4457F3C L-53F3BT WP3A10F3C LTE-4208 IR42-21C/TR8 HSDL-4261 APA3010F3C-GX SE2460-140 OP266-905 OP280D LTE-2871 HIR8323/C16 KP-2012SF4C KPA-3010F3C L-7113SF6C